AU - 303

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M.Sc. Semester-II (CBCS Scheme) Examination PHYSICS

2-PHY-4 (I): Network Theorems and Solid State Devices

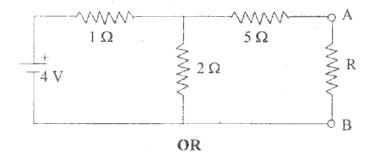
Time: Three Hours

[Maximum Marks: 80

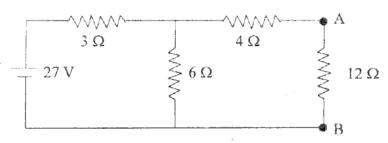
Note: — ALL questions are compulsory and carry equal marks.

- 1. (A) Explain the functions of Capacitor and Inductor in an electrical circuit. 6
 - (B) Discuss the various steps involved for solving network by using Norton's theorem.
 - (C) Find the value of 'R' in the circuit given below, for maximum power transfer to it.

 What is the amount of this power?



- (P) State and explain Kirchhoff's voltage and current law with sign convention. 6
- (Q) Illustrate superposition theorem with suitable example.
- (R) Apply Thevenin's theorem to find current through 12 Ω resistor in the following circuit.



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2.	(A)	Describe the construction of n-channel JFET and explain its working. Obtain relation between FET parameters.	on 8		
	(B)	Explain the formation of depletion region and potential barrier in P-n junction. Whis the effect of forward bias and reverse bias on them?	at 8		
		OR			
	(P)	Explain construction of UJT and negative region in its characteristics. Explain the us of UJT as relaxation oscillator.	se 8		
	(Q)	Give the construction and working of ED-MOSFET (Dual mode MOSFET).	8		
3,	(A)	Explain working of full wave rectifier using two diodes. Show that maximum rectification efficiency of this rectifier is 81.2%.	on 8		
	(B)	Explain the construction and characteristics of SCR. Give any one application detail.	in 8		
		OR			
	(P)	Draw block diagram of regulated power supply. Discuss in detail working of zero regulator circuit with respect to line voltage and load variations.	er 8		
	(Q)	Explain the use of IC-317 as adjustable voltage regulator. Design adjustable voltage regulator using IC-317 for output voltage $V_o = 5$ V to 12 V. Given : current limiting resistor $R = 240 \Omega$, $V_{ref} = 1.25$ V.			
4.	(A)	Explain the action of n-p-n transistor.	4		
	(B)	Explain the different regions of output characteristics of CE-transistor.	6		
	(C)	Draw circuit diagram of two stage RC-coupled amplifier and discuss its gain-frequence response.	су 6		
OR					
	(P)		of 6		
	(Q)	What are different types of noise? Explain thermal noise.	5		
	(R)	Obtain the values of collector current and collector voltage of CE-transistor if $V_{cc}=12$ T $R_{B}=300~k\Omega,~R_{L}=2~k\Omega,~B_{dc}=100.$	V, 5		
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5.	(A)	Describe the construction and working of LVDT.	5
	(B)	Explain with suitable example, the use of NTC thermistor for tem measurement.	perature 5
	(C)	Explain with suitable example, the action of capacitive transducer.	6
		OR	
	(P)	Explain the working of phototransistor.	5
	(Q)	Explain the use of saw tooth waveform signal in CRO.	3
	(R)	What is microphone? Explain working of condenser microphone.	5
	(8)	Draw block diagram of function generator	3

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